NSN 5962-00-271-1695



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-00-271-1695 **Body Length:** 0.825 inches **Body Width:** Between 0.240 inches and 0.290 inches **Body Height:** 0.180 inches **Maximum Power Dissipation Rating:** 525.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs **Inclosure Material:** Ceramic and metal **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 5 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -1.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 90.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 07187-4005817 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a

Demilitarization:

Unit Of Measure:

Yes - demil/mli

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